





SAR TEST REPORT

No. I19Z70001-SEM02

For

Samsung Electronics. Co., Ltd.

Mobile phone

Model Name: SM-M115M/DS, SM-M115M

With

Hardware Version: REV1.0

Software Version: M115M.001(M115MUBE0ATA8)

FCC ID: ZCASMM115M

Issued Date: 2020-2-20

Note:

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REPORT HISTORY

Report Number	Revision	Issue Date	Description
I19Z70001-SEM02	Rev.0	2020-2-20	Initial creation of test report
I19Z70001-SEM02	Rev.1	2020-2-21	 Chapter4.1, revise GPRS/EGPRS Multi-slot Class. Chapter11.2, revise tune up of WCDMA850 HSUPA sub-test5. Chapter12.2, revise the picture of antenna location. Chapter14, revise duty cycle of GPRS&EGPRS for GSM1900.





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1 Test Laboratory

1.1 Testing Location

Company Name:	CTTL(Shouxiang)
Address:	No. 51 Shouxiang Science Building, Xueyuan Road, Haidian District,
	Beijing, P. R. China100191

1.2 Testing Environment

Temperature:	18°C~25°C,
Relative humidity:	30%~ 70%
Ground system resistance:	< 0.5 Ω
Ambient noise & Reflection:	< 0.012 W/kg

1.3 Project Data

Project Leader:	Qi Dianyuan
Test Engineer:	Lin Xiaojun
Testing Start Date:	February 9, 2020
Testing End Date:	February 14, 2020

1.4 Signature

Lin Xiaojun

(Prepared this test report)

Qi Dianyuan

(Reviewed this test report)

Lu Bingsong

Deputy Director of the laboratory

(Approved this test report)





2 Statement of Compliance

The maximum results of Specific Absorption Rate (SAR) found during testing for Samsung Electronics. Co., Ltd. Mobile phone SM-M115M/DS, SM-M115M is as follows:

Table 2.1: Highest Reported SAR (1g)

Exposure	Technology	Highest Reported SAR	Equipment
Configuration	Band	1g(W/kg)	Class
<u> </u>	GSM 850	0.28	
	PCS 1900	0.11	
	UMTS FDD 2	0.09	
	UMTS FDD 4	0.22	
Head	UMTS FDD 5	0.16	
	LTE Band 2	0.08	PCE
(Separation Distance	LTE Band 4	0.11	
0mm)	LTE Band 5	0.16	
	LTE Band 7	0.14	
	LTE Band 12	0.10	
	LTE Band 28	0.08	
	WLAN 2.4 GHz	0.64	DTS
	GSM 850	0.49	
	PCS 1900	0.63	
	UMTS FDD 2	0.83	
	UMTS FDD 4	1.11	
Hotspot	UMTS FDD 5	0.22	
•	LTE Band 2	0.62	PCE
(Separation Distance	LTE Band 4	0.87	
10mm)	LTE Band 5	0.22	
	LTE Band 7	0.61	
	LTE Band 12	0.11	
	LTE Band 28	0.14	
	WLAN 2.4 GHz	0.16	DTS

The SAR values found for the Mobile Phone are below the maximum recommended levels of 1.6 W/kg as averaged over any 1g tissue according to the ANSI C95.1-1992.

For body operation, this device has been tested and meets FCC RF exposure guidelines when used with any accessory that contains no metal and which provides a minimum separation distance of 10 mm between this device and the body of the user. Use of other accessories may not ensure compliance with FCC RF exposure guidelines.

The EUT battery must be fully charged and checked periodically during the test to ascertain uniform power output.

The measurement together with the test system set-up is described in annex C of this test report. A detailed description of the equipment under test can be found in chapter 4 of this test report. The





highest reported SAR value is obtained at the case of (Table 2.1), and the values are: 1.11 W/kg(1g).

Table 2.2: The sum of reported SAR values for main antenna and WiFi 2.4G

	Position	Main antenna	WLAN	Sum
Maximum reported SAR value for Head	Left hand, Touch cheek	0.21	0.67	0.88
Maximum reported SAR value for Body	Bottom	1.11	<0.01	1.11

Table 2.3: The sum of reported SAR values for main antenna and BT

	Position	Main antenna	ВТ	Sum
Maximum reported SAR value for Head	Right hand, Touch cheek	0.28	0.37	0.65
Maximum reported SAR value for Body	Bottom	1.11	0.19 ^[1]	1.30

^{[1] -} Estimated SAR for Bluetooth (see the table 13.3)

According to the above tables, the highest sum of reported SAR values is **1.30 W/kg (1g)**. The detail for simultaneous transmission consideration is described in chapter 13.





3 Client Information

3.1 Applicant Information

Company Name:	Samsung Electronics. Co., Ltd.	
Address/Post:	R5, A Tower 22 Floor A-1,(Maetan dong) 129,Samsung-ro,Yeongtong-	
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3.2 Manufacturer Information

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	gu, Suwon-Si, Gyeonggi-do 16677, Korea
Contact Person:	JP KIM
Contact Email:	jp426.kim@samsung.com
Telephone:	+82-10-4376-0326





4 Equipment Under Test (EUT) and Ancillary Equipment (AE)

4.1 About EUT

Description:	Mobile phone
Model name: SM-A115F/DS	
	GSM850/900/1800/1900,WCDMA850/900/1700/1900/21
Operating mode(s):	00
	LTE Band 1/2/3/4/5/7/8/12/17/28, BT, Wi-Fi(2.4G)
	825 – 848.8 MHz (GSM 850)
	1850.2 – 1910 MHz (GSM 1900)
	826.4-846.6 MHz (WCDMA 850 Band V)
	1710 – 1755 MHz (WCDMA 1700 Band IV)
	1850–1910 MHz (WCDMA1900 Band II)
Tested Tx Frequency:	1860 – 1900 MHz (LTE Band 2)
lested 1x i requericy.	1710 – 1755 MHz (LTE Band 4
	824 – 849 MHz (LTE Band 5)
	2502.5 – 2567.5 MHz (LTE Band 7)
	699 – 716 MHz (LTE Band 12)
	719.5 – 746.5 MHz (LTE Band 28)
	2412 – 2462 MHz (Wi-Fi 2.4G)
GPRS/EGPRS Multislot Class:	33
GPRS capability Class:	В
Test device Production information:	Production unit
Device type:	Portable device
Antenna type:	Integrated antenna

4.2 Internal Identification of EUT used during the test

EUT ID*	IMEI	HW Version	SW Version
EUT1	353692110107207/353692110107205	REV1.0	M115M.001(M115MUBE0ATA8)
EUT2	354555110002099/354555110002097	REV1.0	M115M.001(M115MUBE0ATA8)

^{*}EUT ID: is used to identify the test sample in the lab internally.

Note: It is performed to test SAR with the EUT1 and conducted power with the EUT2.

4.3 Internal Identification of AE used during the test

AE ID*	Description	Model	SN	Manufacturer
Λ [1	Secondary	110 710	,	SCUD(Fujian) Electronics Co.,
AE1	Li-ion Battery	HQ-71S	/	Ltd.
AE2	Secondary	HQ-71S	,	Ningde Amperex Technology
AEZ	Li-ion Battery	ΠQ-/ 13	,	Limited
٨٢٥	Llandant		,	DONGGUAN YOUNGBO
AE3	Headset	EHS61ASFWE	/	ELECTRONICS CO.,LTD
AE4	Headset	EHS61ASFWE		CRESYN VIETNAM CO.,LTD.

^{*}AE ID: is used to identify the test sample in the lab internally.





5 TEST METHODOLOGY

5.1 Applicable Limit Regulations

ANSI C95.1–1992:IEEE Standard for Safety Levels with Respect to Human Exposure to Radio Frequency Electromagnetic Fields, 3 kHz to 300 GHz.

It specifies the maximum exposure limit of **1.6 W/kg** as averaged over any 1 gram of tissue for portable devices being used within 20 cm of the user in the uncontrolled environment.

5.2 Applicable Measurement Standards

IEEE 1528–2013: Recommended Practice for Determining the Peak Spatial-Average Specific Absorption Rate (SAR) in the Human Head from Wireless Communications Devices: Measurement Techniques.

KDB447498 D01: General RF Exposure Guidance v06: Mobile and Portable Devices RF Exposure Procedures and Equipment Authorization Policies.

KDB648474 D04 Handset SAR v01r03: SAR Evaluation Considerations for Wireless Handsets.

KDB941225 D01 SAR test for 3G devices v03r01: SAR Measurement Procedures for 3G Devices

KDB941225 D05 SAR for LTE Devices v02r05: SAR Evaluation Considerations for LTE Devices

KDB941225 D06 Hotspot Mode SAR v02r01: SAR Evaluation Procedures for Portable Devices with Wireless Router Capabilities

KDB248227 D01 802.11 Wi-Fi SAR v02r02: SAR GUIDANCE FOR IEEE 802.11 (Wi-Fi) TRANSMITTERS

KDB865664 D01SAR measurement 100 MHz to 6 GHz v01r04: SAR Measurement Requirements for 100 MHz to 6 GHz.

KDB865664 D02RF Exposure Reporting v01r02: RF Exposure Compliance Reporting and Documentation Considerations





6 Specific Absorption Rate (SAR)

6.1 Introduction

SAR is related to the rate at which energy is absorbed per unit mass in an object exposed to a radio field. The SAR distribution in a biological body is complicated and is usually carried out by experimental techniques or numerical modeling. The standard recommends limits for two tiers of groups, occupational/controlled and general population/uncontrolled, based on a person's awareness and ability to exercise control over his or her exposure. In general, occupational/controlled exposure limits are higher than the limits for general population/uncontrolled.

6.2 SAR Definition

The SAR definition is the time derivative (rate) of the incremental energy (dW) absorbed by (dissipated in) an incremental mass (dm) contained in a volume element (dv) of a given density (ρ). The equation description is as below:

$$SAR = \frac{d}{dt}(\frac{dW}{dm}) = \frac{d}{dt}(\frac{dW}{\rho dv})$$

SAR is expressed in units of Watts per kilogram (W/kg)

SAR measurement can be either related to the temperature elevation in tissue by

$$SAR = c(\frac{\delta T}{\delta t})$$

Where: C is the specific head capacity, δT is the temperature rise and δt is the exposure duration, or related to the electrical field in the tissue by

$$SAR = \frac{\sigma |E|^2}{\rho}$$

Where: σ is the conductivity of the tissue, ρ is the mass density of tissue and E is the RMS electrical field strength.

However for evaluating SAR of low power transmitter, electrical field measurement is typically applied.





7 Tissue Simulating Liquids

7.1 Targets for tissue simulating liquid

Table 7.1: Targets for tissue simulating liquid

Frequency(MHz)	Liquid Type	Conductivity(σ)	± 5% Range	Permittivity(ε)	± 5% Range
750	Head	0.89	0.85~0.93	41.94	39.8~44.0
835	Head	0.90	0.86~0.95	41.5	39.4~43.6
1750	Head	1.37	1.30~1.44	40.08	38.1~42.1
1900	Head	1.40	1.33~1.47	40.0	38.0~42.0
2450	Head	1.80	1.71~1.89	39.2	37.2~41.2
2600	Head	1.96	1.86~2.06	39.01	37.1~41.0

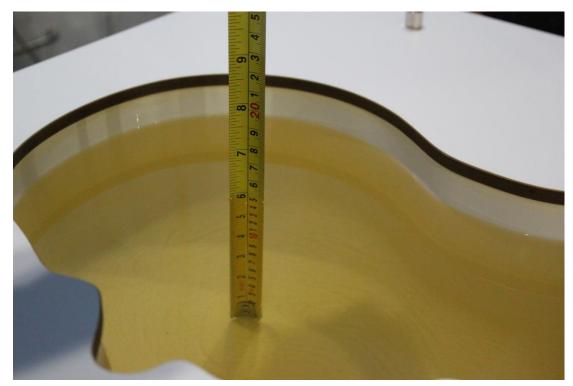
7.2 Dielectric Performance

Table 7.2: Dielectric Performance of Tissue Simulating Liquid

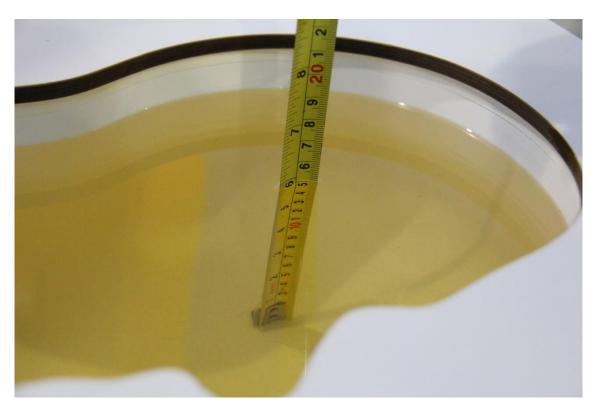
Measurement Date (yyyy-mm-dd)	Туре	Frequency	Permittivity ε	Drift (%)	Conductivity σ (S/m)	Drift (%)
2020/2/9	Head	750 MHz	42.07	0.31	0.897	0.79
2020/2/10	Head	835 MHz	41.45	-0.12	0.884	-1.78
2020/2/11	Head	1750 MHz	39.44	-1.60	1.374	0.29
2020/2/12	Head	1900 MHz	39.33	-1.68	1.382	-1.29
2020/2/13	Head	2450 MHz	39.22	0.05	1.813	0.72
2020/2/14	Head	2600 MHz	38.4	-1.56	1.96	0.00

Note: The liquid temperature is 22.0 $^{\circ}\mathrm{C}$





Picture 7-1 Liquid depth in the Head Phantom (750MHz)

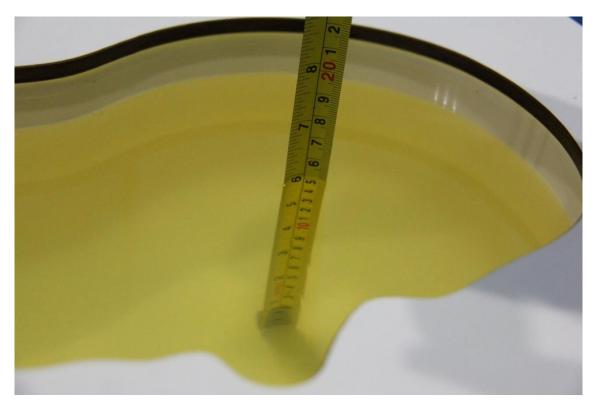


Picture 7-2 Liquid depth in the Head Phantom (835 MHz)



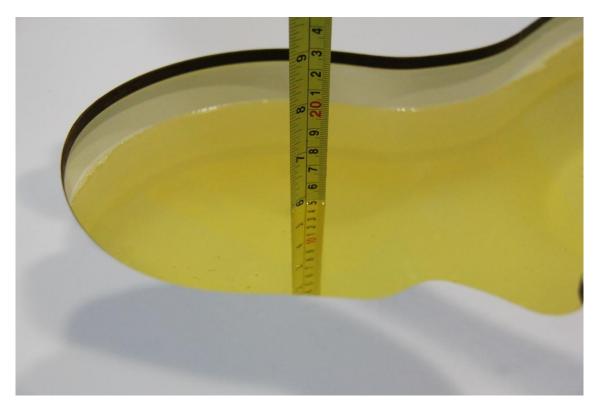


Picture 7-3 Liquid depth in the Head Phantom (1750 MHz)



Picture 7-4 Liquid depth in the Head Phantom (1900 MHz)





Picture 7-5 Liquid depth in the Head Phantom (2450MHz)



Picture 7-6 Liquid depth in the Head Phantom (2600 MHz)

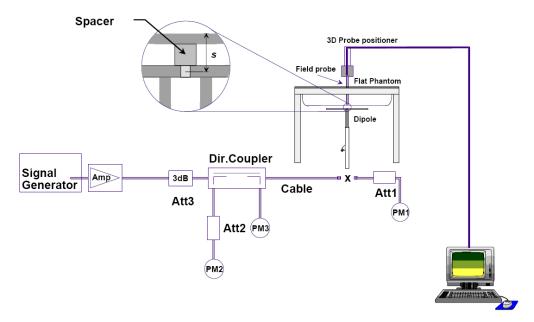




8 System verification

8.1 System Setup

In the simplified setup for system evaluation, the DUT is replaced by a calibrated dipole and the power source is replaced by a continuous wave that comes from a signal generator. The calibrated dipole must be placed beneath the flat phantom section of the SAM twin phantom with the correct distance holder. The distance holder should touch the phantom surface with a light pressure at the reference marking and be oriented parallel to the long side of the phantom. The equipment setup is shown below:



Picture 8.1 System Setup for System Evaluation



Picture 8.2 Photo of Dipole Setup





8.2 System Verification

SAR system verification is required to confirm measurement accuracy, according to the tissue dielectric media, probe calibration points and other system operating parameters required for measuring the SAR of a test device. The system verification must be performed for each frequency band and within the valid range of each probe calibration point required for testing the device.

The system verification results are required that the area scan estimated 1-g SAR is within 3% of the zoom scan 1-g SAR. The details are presented in annex B.

Table 8.1: System Verification of Head

Measurement	Measurement		Target value (W/kg)		value(W/kg)	Deviation	
Date	Frequency	10 g	1 g	10 g	1 g	10 g	1 g
(yyyy-mm-dd)		Average	Average	Average	Average	Average	Average
2020/2/9	750 MHz	5.57	8.57	5.64	8.52	1.26%	-0.58%
2020/2/10	835 MHz	6.29	9.70	6.24	9.76	-0.79%	0.62%
2020/2/11	1750 MHz	19.3	36.6	19.24	36.12	-0.31%	-1.31%
2020/2/12	1900 MHz	20.8	39.7	21.16	39.8	1.73%	0.25%
2020/2/13	2450 MHz	24.2	51.6	23.96	50.88	-0.99%	-1.40%
2020/2/14	2600 MHz	25.1	55.8	25.24	54.68	0.56%	-2.01%





9 Measurement Procedures

9.1 Tests to be performed

In order to determine the highest value of the peak spatial-average SAR of a handset, all device positions, configurations and operational modes shall be tested for each frequency band according to steps 1 to 3 below. A flowchart of the test process is shown in picture 9.1.

Step 1: The tests described in 9.2 shall be performed at the channel that is closest to the centre of the transmit frequency band (f_c) for:

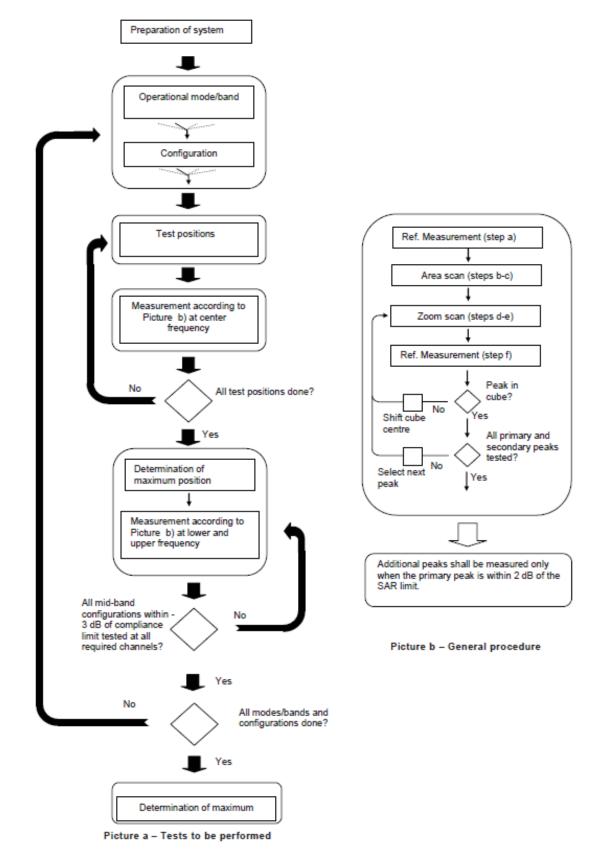
- a) all device positions (cheek and tilt, for both left and right sides of the SAM phantom, as described in annex D),
- b) all configurations for each device position in a), e.g., antenna extended and retracted, and c) all operational modes, e.g., analogue and digital, for each device position in a) and configuration in b) in each frequency band.

If more than three frequencies need to be tested according to 11.1 (i.e., $N_c > 3$), then all frequencies, configurations and modes shall be tested for all of the above test conditions.

Step 2: For the condition providing highest peak spatial-average SAR determined in Step 1,perform all tests described in 9.2 at all other test frequencies, i.e., lowest and highest frequencies. In addition, for all other conditions (device position, configuration and operational mode) where the peak spatial-average SAR value determined in Step 1 is within 3dB of the applicable SAR limit, it is recommended that all other test frequencies shall be tested as well.

Step 3: Examine all data to determine the highest value of the peak spatial-average SAR found in Steps 1 to 2.





Picture 9.1Block diagram of the tests to be performed





9.2 General Measurement Procedure

The area and zoom scan resolutions specified in the table below must be applied to the SAR measurements and fully documented in SAR reports to qualify for TCB approval. Probe boundary effect error compensation is required for measurements with the probe tip closer than half a probe tip diameter to the phantom surface. Both the probe tip diameter and sensor offset distance must satisfy measurement protocols; to ensure probe boundary effect errors are minimized and the higher fields closest to the phantom surface can be correctly measured and extrapolated to the phantom surface for computing 1-g SAR. Tolerances of the post-processing algorithms must be verified by the test laboratory for the scan resolutions used in the SAR measurements, according to the reference distribution functions specified in IEEE Std 1528-2003. The results should be documented as part of the system validation records and may be requested to support test results when all the measurement parameters in the following table are not satisfied.

			≤ 3 GHz	> 3 GHz		
Maximum distance from (geometric center of pro			5 ± 1 mm	$\frac{1}{2} \cdot \delta \cdot \ln(2) \pm 0.5 \text{ mm}$		
Maximum probe angle f normal at the measurem			30° ± 1°	$30^{\circ} \pm 1^{\circ}$ $20^{\circ} \pm 1^{\circ}$ $3 - 4 \text{ GHz} : \leq 12 \text{ mm}$ $3 \text{ GHz} : \leq 12 \text{ mm}$ $4 - 6 \text{ GHz} : \leq 10 \text{ mm}$ e x or y dimension of the test device, in the ment plane orientation, is smaller than the above, the ment resolution must be \leq the corresponding x or y on of the test device with at least one measurement the test device. $3 - 4 \text{ GHz} : \leq 5 \text{ mm}$ $3 - 4 \text{ GHz} : \leq 5 \text{ mm}$		
			≤ 2 GHz: ≤ 15 mm 2 – 3 GHz: ≤ 12 mm	_		
Maximum area scan spa	tial resoluti	on: Δx _{Area} , Δy _{Area}	When the x or y dimension of the test device, in the measurement plane orientation, is smaller than the above, the measurement resolution must be ≤ the corresponding x or y dimension of the test device with at least one measurement point on the test device.			
Maximum zoom scan sp	atial resolu	tion: Δx _{Zoom} , Δy _{Zoom}	≤ 2 GHz: ≤ 8 mm 2 – 3 GHz: ≤ 5 mm*	_		
	uniform g	grid: Δz _{Zoom} (n)	≤ 5 mm	$4-5 \text{ GHz}$: $\leq 3 \text{ mm}$		
Maximum zoom scan spatial resolution, normal to phantom surface	graded	Δz _{Zoom} (1): between 1 st two points closest to phantom surface	≤ 4 mm	$4-5~\text{GHz}; \leq 2.5~\text{mm}$		
	grid	Δz _{Zoom} (n>1): between subsequent points	$\leq 1.5 \cdot \Delta z_{Zoom}(n-1)$			
Minimum zoom scan volume	x, y, z		≥ 30 mm	3 – 4 GHz: ≥ 28 mm 4 – 5 GHz: ≥ 25 mm 5 – 6 GHz: ≥ 22 mm		

Note: δ is the penetration depth of a plane-wave at normal incidence to the tissue medium; see draft standard IEEE P1528-2011 for details.

When zoom scan is required and the <u>reported</u> SAR from the area scan based *I-g SAR estimation* procedures of KDB 447498 is ≤ 1.4 W/kg, ≤ 8 mm, ≤ 7 mm and ≤ 5 mm zoom scan resolution may be applied, respectively, for 2 GHz to 3 GHz, 3 GHz to 4 GHz and 4 GHz to 6 GHz.





9.3 WCDMA Measurement Procedures for SAR

The following procedures are applicable to WCDMA handsets operating under 3GPP Release99, Release 5 and Release 6. The default test configuration is to measure SAR with an established radio link between the DUT and a communication test set using a 12.2kbps RMC (reference measurement channel) configured in Test Loop Mode 1. SAR is selectively confirmed for other physical channel configurations (DPCCH & DPDCH_n), HSDPA and HSPA (HSUPA/HSDPA) modes according to output power, exposure conditions and device operating capabilities. Both uplink and downlink should be configured with the same RMC or AMR, when required. SAR for Release 5 HSDPA and Release 6 HSPA are measured using the applicable FRC (fixed reference channel) and E-DCH reference channel configurations. Maximum output power is verified according to applicable versions of 3GPP TS 34.121 and SAR must be measured according to these maximum output conditions. When Maximum Power Reduction (MPR) is not implemented according to Cubic Metric (CM) requirements for Release 6 HSPA, the following procedures do not apply.

For Release 5 HSDPA Data Devices:

Sub-test	$oldsymbol{eta_c}$	$oldsymbol{eta}_d$	β_d (SF)	β_c/β_d	$oldsymbol{eta_{hs}}$	CM/dB
1	2/15	15/15	64	2/15	4/15	0.0
2	12/15	15/15	64	12/15	24/25	1.0
3	15/15	8/15	64	15/8	30/15	1.5
4	15/15	4/15	64	15/4	30/15	1.5

For Release 6 HSPA Data Devices

Sub-	$oldsymbol{eta_c}$	$eta_{\!\scriptscriptstyle d}$	β_d (SF)	$oldsymbol{eta_c}$ / $oldsymbol{eta_d}$	$oldsymbol{eta_{hs}}$	$oldsymbol{eta_{ec}}$	$oldsymbol{eta}_{ed}$	eta_{ed}	$oldsymbol{eta_{ed}}$ (codes)	CM (dB)	MPR (dB)	AG Index	E- TFCI
1	11/15	15/15	64	11/15	22/15	209/225	1039/225	4	1	1.5	1.5	20	75
2	6/15	15/15	64	6/15	12/15	12/15	12/15	4	1	1.5	1.5	12	67
3	15/15	9/15	64	15/9	30/15	30/15	$eta_{ed1:47/15} \ eta_{ed2:47/15}$	4	2	1.5	1.5	15	92
4	2/15	15/15	64	2/15	4/15	4/15	56/75	4	1	1.5	1.5	17	71
5	15/15	15/15	64	15/15	24/15	30/15	134/15	4	1	1.5	1.5	21	81

Rel.8 DC-HSDPA (Cat 24)

SAR test exclusion for Rel.8 DC-HSDPA must satisfy the SAR test exclusion requirements of Rel.5 HSDPA. SAR test exclusion for DC-HSDPA devices is determined by power measurements according to the H-Set 12, Fixed Reference Channel (FRC) configuration in Table C.8.1.12 of 3GPP TS 34.121-1. A primary and a secondary serving HS-DSCH Cell are required to perform the power measurement and for the results to qualify for SAR test exclusion.





9.4 SAR Measurement for LTE

SAR tests for LTE are performed with a base station simulator, Rohde & Rchwarz CMW500. Closed loop power control was used so the UE transmits with maximum output power during SAR testing. All powers were measured with the CMW 500.

It is performed for conducted power and SAR based on the KDB941225 D05.

SAR is evaluated separately according to the following procedures for the different test positions in each exposure condition – head, body, body-worn accessories and other use conditions. The procedures in the following subsections are applied separately to test each LTE frequency band.

- 1) QPSK with 1 RB allocation
 Start with the largest channel bandwidth and measure SAR for QPSK with 1 RB allocation, using the RB offset and required test channel combination with the highest maximum output power among RB offsets at the upper edge, middle and lower edge of each required test channel. When the reported SAR is ≤ 0.8 W/kg, testing of the remaining RB offset configurations and required test channels is not required for 1 RB allocation; otherwise, SAR is required for the remaining required test channels and only for the RB offset configuration with the highest output power for that channel. When the reported SAR of a required test channel is > 1.45 W/kg, SAR is required for all three RB offset configurations for that required test channel.
- 2) QPSK with 50% RB allocation The procedures required for 1 RB allocation in 1) are applied to measure the SAR for QPSK with 50% RB allocation.
- 3) QPSK with 100% RB allocation
 - For QPSK with 100% RB allocation, SAR is not required when the highest maximum output power for 100 % RB allocation is less than the highest maximum output power in 50% and 1 RB allocations and the highest reported SAR for 1 RB and 50% RB allocation in 1) and 2) are \leq 0.8 W/kg. Otherwise, SAR is measured for the highest output power channel; and if the reported SAR is > 1.45 W/kg, the remaining required test channels must also be tested.





9.5 Bluetooth & Wi-Fi Measurement Procedures for SAR

Normal network operating configurations are not suitable for measuring the SAR of 802.11 transmitters in general. Unpredictable fluctuations in network traffic and antenna diversity conditions can introduce undesirable variations in SAR results. The SAR for these devices should be measured using chipset based test mode software to ensure that the results are consistent and reliable.

Chipset based test mode software is hardware dependent and generally varies among manufacturers. The device operating parameters established in a test mode for SAR measurements must be identical to those programmed in production units, including output power levels, amplifier gain settings and other RF performance tuning parameters. The test frequencies should correspond to actual channel frequencies defined for domestic use. SAR for devices with switched diversity should be measured with only one antenna transmitting at a time during each SAR measurement, according to a fixed modulation and data rate. The same data pattern should be used for all measurements.

9.6 Power Drift

To control the output power stability during the SAR test, DASY4 system calculates the power drift by measuring the E-field at the same location at the beginning and at the end of the measurement for each test position. These drift values can be found in section14 labeled as: (Power Drift [dB]). This ensures that the power drift during one measurement is within 5%.





10 Area Scan Based 1-g SAR

10.1 Requirement of KDB

According to the KDB447498 D01, when the implementation is based the specific polynomial fit algorithm as presented at the 29th Bioelectromagnetics Society meeting (2007) and the estimated 1-gSAR is \leq 1.2 W/kg, a zoom scan measurement is not required provided it is also not needed for any other purpose; for example, if the peak SAR location required for simultaneous transmission SAR test exclusion can be determined accurately by the SAR system or manually to discriminate between distinctive peaks and scattered noisy SAR distributions from area scans.

There must not be any warning or alert messages due to various measurement concerns identified by the SAR system; for example, noise in measurements, peaks too close to scan boundary, peaks are too sharp, spatial resolution and uncertainty issues etc. The SAR system verification must also demonstrate that the area scan estimated 1-g SAR is within 3% of the zoom scan 1-g SAR (See Annex B). When all the SAR results for each exposure condition in a frequency band and wireless mode are based on estimated 1-g SAR, the 1-g SAR for the highest SAR configuration must be determined by a zoom scan.

10.2 Fast SAR Algorithms

The approach is based on the area scan measurement applying a frequency dependent attenuation parameter. This attenuation parameter was empirically determined by analyzing a large number of phones. The MOTOROLA FAST SAR was developed and validated by the MOTOROLA Research Group in Ft. Lauderdale.

In the initial study, an approximation algorithm based on Linear fit was developed. The accuracy of the algorithm has been demonstrated across a broad frequency range (136-2450 MHz)and for both 1- and 10-g averaged SAR using a sample of 264 SAR measurements from 55wireless handsets. For the sample size studied, the root-mean-squared errors of the algorithm mare 1.2% and 5.8% for 1- and 10-g averaged SAR, respectively. The paper describing the algorithm in detail is expected to be published in August 2004 within the Special Issue of Transactions on MTT.

In the second step, the same research group optimized the fitting algorithm to an Polynomial fit whereby the frequency validity was extended to cover the range 30-6000MHz. Details of this study can be found in the BEMS 2007 Proceedings.

Both algorithms are implemented in DASY software.





11 Conducted Output Power

11.1 GSM Measurement result

During the process of testing, the EUT was controlled via Agilent Digital Radio Communication tester (E5515C) to ensure the maximum power transmission and proper modulation. This result contains conducted output power for the EUT. In all cases, the measured peak output power should be greater and within 5% than EMI measurement.

Table 11.1-1: The conducted power measurement results for GSM

GSM 850	Measur	ed Power	(dBm)	Tune up	calculation	Averag	ged Power	r (dBm)	
Speech (GMSK)	251	190	128			251	190	128	
1 Txslot	32.31	32.46	32.25	34.00	1	/	1	1	
GSM 850	Measur	ed Power	(dBm)		calculation	Averag	ged Power	(dBm)	
GPRS (GMSK)	251	190	128			251	190	128	
1Txslot	32.37	32.40	32.18	34.00	-9.03	23.34	23.37	23.15	
2Txslots	29.71	29.98	29.99	31.00	-6.02	23.69	23.96	23.97	
3Txslots	27.90	28.07	28.14	29.50	-4.26	23.64	23.81	23.88	
4Txslots	27.12	27.28	27.43	28.50	-3.01	24.11	24.27	24.42	
GSM 850	Measur	ed Power	(dBm)		calculation	Averag	jed Power	(dBm)	
EGPRS (GMSK)	251	190	128			251	190	128	
1Txslot	32.31	32.43	32.22	34.00	-9.03	23.28	23.40	23.19	
2Txslots	29.62	29.94	29.94	31.00	-6.02	23.60	23.92	23.92	
3Txslots	27.84	28.06	28.17	29.50	-4.26	23.58	23.80	23.91	
4Txslots	27.05	27.33	27.51	28.50	-3.01	24.04	24.32	24.50	
GSM 850	Measur	ed Power	(dBm)		calculation	Averag	Averaged Power (dBm)		
EGPRS (8PSK)	251	190	128			251	190	128	
1Txslot	25.67	25.73	26.03	28.00	-9.03	16.64	16.70	17.00	
2Txslots	23.01	23.28	23.55	25.00	-6.02	16.99	17.26	17.53	
3Txslots	21.81	22.08	22.26	23.00	-4.26	17.55	17.82	18.00	
4 Txslots	21.57	21.86	22.06	23.00	-3.01	18.56	18.85	19.05	
PCS1900	Measur	ed Power	(dBm)	Tune	calculation	Averag	jed Power	(dBm)	
Speech (GMSK)				up					
	810	661	512			810	661	512	
1 Txslot	29.56	29.62	29.21	31.00	1	/	/	/	
PCS1900	Measur	ed Power	(dBm)		calculation	Averag	jed Power	(dBm)	
GPRS (GMSK)	810	661	512			810	661	512	
1Txslot	29.64	29.58	29.15	30.50	-9.03	20.61	20.55	20.12	
2Txslots	27.67	27.93	27.53	28.50	-6.02	21.65	21.91	21.51	
3Txslots	25.47	25.45	24.99	25.50	-4.26	21.21	21.19	20.73	
4Txslots	24.39	24.62	24.23	25.00	-3.01	21.38	21.61	21.22	
PCS1900	Measur	ed Power	(dBm)		calculation	Averag	Averaged Power (dBm)		
EGPRS (GMSK)	810	661	512			810	661	512	
1Txslot	29.54	29.54	29.16	30.50	-9.03	20.51	20.51	20.13	





2Txslots	27.68	27.96	27.46	28.50	-6.02	21.66	21.94	21.44
3Txslots	25.40	25.49	25.01	25.50	-4.26	21.14	21.23	20.75
4Txslots	24.33	24.65	24.15	25.00	-3.01	21.32	21.64	21.14
PCS1900	Measured Power (dBm)				calculation	Averaged Power (dBm)		(dBm)
EGPRS (8PSK)	810	661	512			810	661	512
1Txslot	25.17	25.40	26.10	27.00	-9.03	16.14	16.37	17.07
2Txslots	23.10	23.23	24.16	24.50	-6.02	17.08	17.21	18.14
3Txslots	21.41	21.53	21.08	23.00	-4.26	17.15	17.27	16.82
4Txslots	20.21	20.37	20.01	22.00	-3.01	17.20	17.36	16.91

NOTES:

1) Division Factors

To average the power, the division factor is as follows:

1TX-slot = 1 transmit time slot out of 8 time slots=> conducted power divided by (8/1) => -9.03dB

2TX-slots = 2 transmit time slots out of 8 time slots=> conducted power divided by (8/2) => -6.02dB

3TX-slots = 3 transmit time slots out of 8 time slots=> conducted power divided by (8/3) => -4.26dB

4TX-slots = 4 transmit time slots out of 8 time slots=> conducted power divided by (8/4) => -3.01dB

According to the conducted power as above, the body measurements are performed with 4Txslots for GSM850 and 2Txslots for GSM1900.

11.2 WCDMA Measurement result

Table 11.2-1: The conducted Power for WCDMA

	band		FDDV resul	t			
Item	ARFCN	4233 (846.6MHz)	4182 (836.4MHz)	4132 (826.4MHz)	Tune up		
WCDMA	\	23.31	23.27	23.35	25.00		
	1	23.18	23.27	23.29	23.90		
	2	21.89	21.12	21.89	22.00		
HSUPA	3	21.39	21.38	21.35	22.00		
	4	23.12	22.32	22.57	23.20		
	5	22.07	22.11	22.41	24.00		
	1	20.08	20.29	20.43	24.20		
DC-HSDPA	2	21.12	21.17	21.36	24.20		
DC-HSDPA	3	20.07	20.29	20.41	23.70		
	4	21.94	22.21	22.29	23.70		
	band	FDDIV result					
Item	ARFCN	1513 (1752.6MHz)	1412 (1732.4MHz)	1312 (1712.4MHz)	Tune up		
WCDMA	1	22.89	23.09	23.19	23.50		
	1	21.48	21.53	21.65	22.50		
	2	21.23	21.32	21.33	21.50		
HSUPA	3	21.43	21.46	21.45	21.50		
	4	21.50	21.54	21.60	21.80		
	5	20.41	20.44	20.53	22.80		





	1	18.72	18.80	18.88	22.90
DC-HSDPA	2	19.42	19.53	19.57	22.90
рс-порга	3	18.37	18.50	18.57	22.40
	4	20.33	20.38	20.37	22.40
	band		FDDII resul	t	
Item	ARFCN	9538 (1907.6MHz)	9400 (1880MHz)	9262 (1852.4MHz)	Tune up
WCDMA	/	22.92	23.22	22.95	23.50
	1	21.50	21.37	21.43	22.50
	2	21.25	21.22	21.39	21.50
HSUPA	3	21.50	21.43	21.38	21.50
	4	21.49	21.41	21.44	21.80
	5	20.51	20.36	20.14	22.80
	1	18.90	18.76	18.94	22.90
DC-HSDPA	2	19.58	19.47	19.50	22.90
DC-HSDPA	3	18.64	18.49	18.52	22.40
	4	20.32	20.17	20.25	22.40

11.3 LTE Measurement result

Table 11.3-1: Maximum Power Reduction (MPR) for LTE

	Channel bandwidth / Transmission bandwidth configuration [RB]						
Modulation	1.4	3	5	10	15	20	MPR (dB)
	MHz	MHz	MHz	MHz	MHz	MHz	
QPSK	> 5	> 4	> 8	> 12	> 16	> 18	1
16 QAM	≤ 5	≤ 4	≤ 8	≤ 12	≤ 16	≤ 18	1
16 QAM	> 5	> 4	> 8	> 12	> 16	> 18	2
64 QAM	≤ 5	≤ 4	≤ 8	≤ 12	≤ 16	≤ 18	2
64 QAM	> 5	> 4	> 8	> 12	> 16	> 18	3

Table 11.3-2: The tune up for LTE

Band	Tune up		
LTE Band 2	23.5		
LTE Band 4	23.5		
LTE Band 5	24		
LTE Band 7	23.2		
LTE Band 12	24		
LTE Band 28	24		



Table 11.3-4: The conducted Power for LTE

	Band 2							
	RB			40044	C40AB4			
Bandwidth	allocation	Frequency	QPSK	16QAM	64QAM			
(MHz)	RB offset	(MHz)	Actual output	Actual output	Actual			
(**************************************	(Start	(**************************************	power (dBm)	power (dBm)	output power			
	RB)	1909.3	22.46	21.93	(dBm) 20.83			
	1RB	1880	22.84	21.88	20.47			
	High (5)	1850.7	22.86	21.83	20.85			
	1RB	1909.3	22.49	22.18	20.75			
	Middle	1880	22.88	21.89	20.74			
	(3)	1850.7	22.88	21.93	20.70			
		1909.3	22.43	22.17	20.86			
	1RB	1880	22.77	21.86	20.67			
	Low (0)	1850.7	22.69	22.00	20.78			
		1909.3	22.64	22.09	20.84			
1.4 MHz	3RB	1880	22.90	21.80	20.73			
	High (3)	1850.7	22.79	22.00	20.83			
	3RB	1909.3	22.65	22.22	21.00			
	Middle	1880	22.92	21.75	20.81			
	(1)	1850.7	22.86	22.23	20.86			
	3RB Low (0)	1909.3	22.58	22.26	20.93			
		1880	22.77	21.87	20.89			
		1850.7	22.78	22.33	20.43			
	6RB (0)	1909.3	21.90	21.19	19.81			
		1880	22.14	21.21	19.71			
	(0)	1850.7	22.00	21.29	19.74			
	1RB High (14) 1RB Middle (7)	1908.5	22.41	21.65	20.45			
		1880	22.66	21.86	20.53			
		1851.5	22.58	22.06	20.62			
		1908.5	22.69	21.96	20.64			
		1880	22.75	22.05	20.89			
		1851.5	22.70	22.08	20.78			
	1RB	1908.5	22.52	21.62	20.56			
	Low (0)	1880	22.62	21.90	20.63			
	, ,	1851.5	22.69	21.78	20.52			
0.8411	8RB	1908.5	21.93	20.70	19.91			
3 MHz	High (7)	1880	22.09	21.09	19.88			
		1851.5	21.98 21.87	21.34	19.72			
	8RB	1908.5		20.72	19.83			
	Middle (4)	1880	22.15 22.00	21.00 21.38	19.75 19.67			
	(**)	1851.5	21.87	21.36	19.88			
	8RB	1908.5 1880	22.06	20.77	19.66			
	Low (0)	1851.5	21.98	21.19	19.49			
		1908.5	21.89	20.92	19.76			
	15RB	1880	22.17	20.94	19.79			
	(0)	1851.5	22.03	21.19	19.76			
	l	1001.0	22.00	£1.10	10.70			



	1 1	4007.5	20.77	24.04	20.70
	1RB	1907.5	22.77	21.84	20.79
	High (24)	1880	22.77	21.60	20.56
		1852.5	22.74	21.59	20.54
	1RB	1907.5	23.14	21.81	20.83
	Middle	1880	23.49	22.23	20.87
	(12)	1852.5	22.95	21.66	20.78
	1RB	1907.5	22.58	21.55	20.52
	Low (0)	1880	22.74	21.55	20.44
		1852.5	22.65	21.48	20.72
	12RB	1907.5	22.04	20.94	19.66
5 MHz	High (13)	1880	22.18	20.98	19.84
	1.19.1 (10)	1852.5	22.07	20.94	19.71
	12RB	1907.5	22.08	20.96	19.66
	Middle	1880	22.32	21.07	19.85
	(6)	1852.5	22.07	21.06	19.65
	4000	1907.5	21.95	20.80	19.58
	12RB	1880	22.14	20.98	19.80
	Low (0)	1852.5	22.06	20.93	19.62
	0.500	1907.5	21.99	20.82	19.83
	25RB	1880	22.16	21.16	19.84
	(0)	1852.5	22.11	21.19	19.83
	1RB High (49)	1905	22.77	21.78	20.78
		1880	22.86	22.08	20.89
		1855	22.63	21.93	20.75
	1RB	1905	22.50	21.64	20.72
	Middle (24)	1880	23.09	22.34	20.80
		1855	22.93	22.36	20.96
	1RB Low (0)	1905	22.82	21.65	20.65
		1880	22.76	22.05	20.66
		1855	22.75	21.93	20.68
	25RB High (25)	1905	21.97	21.03	19.77
10 MHz		1880	22.09	21.47	19.58
10 IVITZ		1855	22.07	21.16	19.76
	0500	1905	22.03	20.92	19.98
	25RB Middle	1880	22.14	21.21	19.98
	(12)		22.07	21.12	19.78
	(12)	1855	21.97	20.85	19.76
	25RB	1905	21.97	20.65	19.59
	Low (0)	1880	22.10	21.14	19.62
		1855			
	50RB (0)	1905	21.96	20.87	19.76
		1880	22.20	21.20	19.86
		1855	22.07	21.06	19.92
	100	1902.5	22.59	22.10	20.78
	1RB High (74)	1880	22.99	22.07	20.84
15 M⊔→	1 11911 (7 1)	1857.5	22.62	21.81	20.54
15 MHz	1RB	1902.5	23.16	21.63	20.51
	Middle	1880	23.20	21.75	20.69
	(37)	1857.5	23.07	21.97	20.81





	 	4000 5	00.74	04.00	20.50
	1RB	1902.5	22.74	21.93	20.52
	Low (0)	1880	22.92	21.95	20.65
	,	1857.5	22.70	21.48	20.67
	36RB	1902.5	22.01	20.89	19.88
	High (38)	1880	22.20	21.21	19.86
	riigir (00)	1857.5	22.16	21.11	19.94
	36RB	1902.5	22.11	21.02	19.70
	Middle	1880	22.23	21.19	19.85
	(19)	1857.5	22.15	21.21	19.95
	0000	1902.5	22.16	21.05	19.73
	36RB	1880	22.16	21.12	19.87
	Low (0)	1857.5	22.10	20.98	19.74
		1902.5	22.09	20.98	19.57
	75RB	1880	22.20	21.15	19.76
	(0)	1857.5	22.09	21.02	19.71
	1RB High (99)	1900	22.65	22.06	20.69
		1880	23.42	21.81	20.56
		1860	22.50	21.85	20.49
	1RB Middle (50)	1900	22.94	22.38	20.54
		1880	23.12	22.03	20.76
		1860	22.92	21.96	20.77
	1RB Low (0)	1900	22.45	21.81	20.60
		1880	22.85	21.83	20.54
		1860	22.39	21.81	20.69
	50RB High (50)	1900	22.02	21.07	19.70
20 MHz		1880	22.21	21.22	19.70
		1860	22.26	21.04	19.72
	50RB	1900	22.22	21.25	19.81
	Middle (25)	1880	22.24	21.24	19.80
		1860	22.10	20.98	19.83
		1900	22.21	21.21	19.68
	50RB Low (0)	1880	22.21	21.02	19.55
		1860	22.18	20.89	19.86
		1900	22.17	21.07	19.60
	100RB	1880	22.26	21.13	19.81
	(0)	1860	22.16	21.01	19.92



	RB		ODOK	400414	040404
Bandwidth (MHz)	allocation		QPSK	16QAM	64QAM
	RB offset	Frequency (MHz)	Actual output	Actual output	Actual output power
()	(Start RB)	(power (dBm)	power (dBm)	(dBm)
	IND)	1754.3	22.59	21.59	20.65
	1RB	1734.5	22.68	21.79	21.07
	High (5)	1732.3	22.74	22.16	20.82
	1RB	1754.3	22.69	21.54	20.59
	Middle	1732.5	22.81	21.87	21.11
	(3)	1710.7	22.94	22.10	20.69
		1754.3	22.45	21.50	20.60
	1RB	1734.5	22.65	21.85	20.54
	Low (0)	1732.3	22.75	22.08	20.75
		1710.7	22.43	21.70	20.70
1.4 MHz	3RB	1734.5	22.53	21.70	20.76
1.T WII 12	High (3)	1732.3	22.78	21.95	20.97
	200	1710.7	22.55	21.72	20.83
	3RB Middle (1)	1734.5	22.63	21.66	20.79
		1732.3	22.87	22.00	21.02
	3RB Low (0)	1710.7	22.41	21.84	20.67
		+		21.70	
		1732.5 1710.7	22.66 23.07	21.70	20.76 20.95
	6RB (0)	+			
		1754.3 1732.5	21.82	20.63	19.49
		1732.5	21.86	20.91 21.17	19.62 19.52
		1710.7	22.09 22.49	21.17	20.45
	1RB	1733.5	22.49	21.64	20.45
	High (14)	1732.5	22.98	22.22	20.61
	400	1711.5	22.81	21.84	20.60
	1RB Middle	1733.5	22.56	21.92	20.74
	(7)	1		1	
	(-,	1711.5 1753.5	23.16	22.24	21.08
	1RB	1753.5 1732.5	22.59 22.49	21.59 21.78	20.19 20.51
	Low (0)			21.78	20.51
		1711.5 1753.5	22.95		20.53 19.56
3 MHz	8RB	1733.5	21.79	20.83	19.56
O IVII IZ	High (7)	1732.5	21.92 22.35	21.05 21.37	19.66
	000	1711.5	22.35	21.01	19.79
	8RB Middle		22.01	20.62	19.73
	(4)	1732.5 1711.5	22.01	21.30	19.73
	(' /	1711.5	22.19	20.58	19.94 19.61
	8RB		21.87		19.62
	Low (0)	1732.5		20.60 21.32	19.82
		1711.5 1753.5	22.25 21.84	20.81	19.68
	15RB	1753.5			
	(0)	1732.5 1711.5	21.94 22.22	20.75 21.14	19.71 19.75



1RB High (24) 1752.5 22.67 21.42 20.76 1RB High (24) 1732.5 22.53 21.43 20.53 1RB Middle (12) 1752.5 23.31 21.40 20.87 1RB Middle (12) 1732.5 22.72 21.67 21.11 1RB Low (0) 1752.5 23.37 22.01 20.87 1RB Low (0) 1752.5 22.29 20.82 20.46 1732.5 22.44 21.49 20.69 1712.5 23.01 21.74 20.70 12RB High (13) 1752.5 21.97 20.74 19.50 12RB High (13) 1732.5 21.91 20.84 19.84 1712.5 22.13 21.26 19.58 12RB Middle (6) 1732.5 21.91 20.89 19.61 12RB Low (0) 1752.5 21.86 20.82 19.59 12RB Low (0) 1732.5 21.92 20.99 19.60 1712.5 22.19 21.20 19.64	
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LOW (U)	
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25RB 1732.5 21.00 21.15 10.87	
(0) 1732.5 21.90 21.13 19.87 1712.5 22.17 21.28 19.96	
1750 22.67 21.90 20.80	
1RB 4722.5 22.50 22.00 20.77	
High (49) 1732.5 22.59 22.09 20.77 1715 22.60 21.77 20.84	
1713 22.00 21.77 20.34 1RB 1750 22.33 21.84 20.72	
Middle 1732.5 22.69 22.43 20.74	
(0.1)	
1710 20.20 21.70 21.00	
1RB 1750 22.47 21.75 20.75	
Low (0) 1732.5 22.56 21.66 20.70	
1715 22.92 21.46 20.81	
25RB 1750 21.83 20.97 19.50	
10 MHz 1732.5 1732.5 21.89 20.88 20.03	
1715 22.12 21.11 19.80	
25RB 1750 21.76 20.89 19.99	
Middle 1732.5 21.90 20.90 20.00	
(12) 1715 22.13 21.18 20.09	
25RB 1750 21.76 20.77 19.93	
Low (0) 1732.5 21.91 20.90 19.94	
1715 22.23 21.28 19.71	
50RB 1750 21.83 20.72 19.69	
(0) 1732.5 21.94 20.85 19.68	
1715 22.13 21.10 19.90	
1RB 1747.5 22.37 22.39 20.76	
High (74) 1732.5 22.76 21.67 21.20	
15 MHz 1717.5 22.72 21.50 21.01	
18B 1747.5 22.38 22.37 20.95	
Middle 1732.5 22.88 22.43 21.10	
(37) 1717.5 22.72 21.89 20.64	





	,				
	1RB	1747.5	22.55	22.49	20.91
	Low (0)	1732.5	22.95	21.82	20.77
		1717.5	22.82	21.92	20.80
		1747.5	21.84	20.92	19.73
	36RB High (38)	1732.5	21.94	20.92	19.83
	1 ligit (50)	1717.5	21.95	21.15	19.91
	36RB Middle (19) 36RB Low (0)	1747.5	21.79	20.79	19.75
		1732.5	21.90	20.84	19.82
		1717.5	22.09	21.11	19.93
		1747.5	21.89	20.81	19.90
		1732.5	21.91	20.79	19.68
		1717.5	22.01	21.04	19.94
		1747.5	21.84	20.77	19.76
		1732.5	21.92	20.93	19.99
	(0)	1717.5	22.02	21.12	20.03
	1RB High (99)	1745	22.46	21.54	20.70
		1732.5	22.26	21.18	20.82
		1720	22.30	21.55	20.76
	1RB Middle (50)	1745	22.74	21.61	20.63
20 MHz		1732.5	22.71	21.73	20.83
		1720	22.70	22.13	20.77
	1RB Low (0)	1745	22.52	21.59	21.02
		1732.5	22.35	21.72	20.93
		1720	22.28	21.59	20.79
	50RB High (50)	1745	21.75	20.88	19.80
		1732.5	21.84	20.84	19.95
		1720	21.97	21.04	19.90
	50RB Middle (25)	1745	21.75	20.68	19.79
		1732.5	21.87	20.89	19.92
		1720	22.02	21.18	19.84
	5000	1745	21.84	20.86	19.92
	50RB	1732.5	21.89	20.82	19.83
	Low (0)	1720	22.02	21.10	19.84
	40000	1745	21.85	20.75	19.93
	100RB - (0) -	1732.5	21.83	21.01	19.84
		1720	22.04	21.05	20.04